



SANYO Semiconductors

DATA SHEET

LA1845NV — Monolithic Linear IC

Single-Chip Home Stereo IC

The LA1845NV is designed for use in mini systems and is a single-chip tuner IC that provides electronic tuning functions using SD/IF-count technique. It incorporates a pilot canceler and an adjustment-free MUX VCO circuit, thus allows additional parts to be reduced.

Functions

- AM : RF amplifier, mixer, oscillator, IF amplifier, detector, AGC, SD, oscillator buffer, IF buffer, stereo IF output, AGC time constant switch
- FM IF : IF amplifier, quadrature detector, S-meter, SD (signal detection), S-curve detection, IF buffer output
- MPX : PLL stereo decoder, stereo display, forced monaural, VCO stop, audio muting, adjacent channel interference rejection function, pilot canceler

Features

- Integrated MPX VCO (ceramic resonators are no longer required.)
- Built-in adjacent channel interference rejection function (114kHz, 190kHz)
- Supports both SD and IF-count techniques
- Both FM SD sensitivity and bandwidth can be set
- Pilot canceler built in.

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Power Supply Voltage	V _{CC} max		6	V
Allowable Power Consumption	P _d max	Ta = 80°C with board 114.3mm×76.1mm×1.6mm material : Glass epoxy resin	360	mW
Operating Temperature	T _{opr}		-20 to +80	°C
Storage Temperature	T _{stg}		-40 to +125	°C

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended Supply Voltage	V _{CC}		5	V
Operating Supply Voltage Range	V _{CC} op	Ta = 80°C	4.3 to 5.5	V

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SANYO Semiconductor Co., Ltd.

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

LA1845NV

Electrical Characteristics • Operating Characteristics at $V_{CC} = 8V$, in the specified test circuit.

FM Mono Characteristics at $f_c = 10.7MHz$, $V_i = 100dB\mu$, $f_m = 1kHz$, Modulation = 75kHz

Parameter	Conditions	Ratings			Unit
		min	typ	max	
Current Drain	With no input signal	20	30	40	mA
Demodulator Output	100dB μ , 100% modulation, $f_m = 1kHz$	230	360	460	mVrms
Total Harmonic Distortion	100dB μ , 100% modulation, $f_m = 1kHz$		0.35	1.5	%
Signal-to-Noise Ratio	100dB μ , 100% modulation, $f_m = 1kHz$	73	80		dB
AM Rejection Ratio	100dB μ , AM = 30% modulation, $f_m = 1kHz$	47	65		dB
3dB Sensitivity	100dB μ , 100% modulation, $f_m = 1kHz$ Output reference, -3dB input		32	40	dB μ
SD Sensitivity	0% modulation	38	47	56	dB μ
IF Counter Buffer Output	100dB μ	200	275	400	mVrms
Mute Attenuation	100dB μ , 100% modulation, $f_m = 1kHz$		76		dB

FM Stereo Characteristics at $f_c = 10.7MHz$, $V_i = 100dB\mu$, L+R = 90%, Pilot = 10%, $f_m = 1kHz$

Parameter	Conditions	Ratings			Unit
		min	typ	max	
Separation	L+R = 90%, Pilot = 10%, $f_m = 1kHz$	30	42		dB
Stereo On Level	Pilot input	1.5	3.5	5.5	%
Total Harmonic Distortion	Pilot input		0.45	1.5	%
Adjacent Channel Rejection Ratio 1	$f_s = 113kHz$, VS = 90%, Pilot = 10% ; The left-right modulation, demodulated output		36		dB
Adjacent Channel Rejection Ratio 2	$f_s = 189kHz$, VS = 90%, Pilot = 10% ; The left-right modulation, demodulated output		41		dB
Carrier Leak	L+R = 90%, Pilot = 10% reference, Pilot = 10% output	38	44		dB

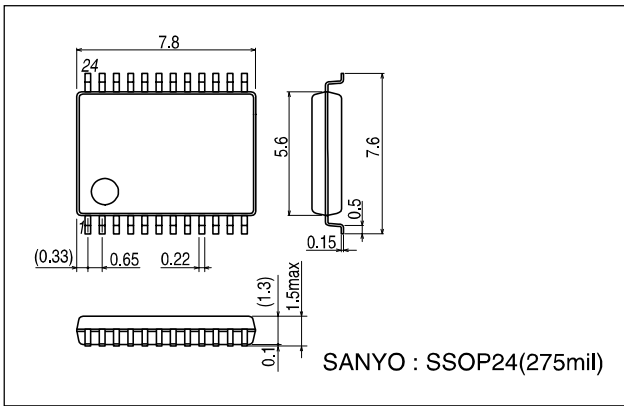
AM Characteristics at $f_c = 1000kHz$, $V_i = 80dB\mu$, $f_m = 1kHz$, Modulation = 30%

Parameter	Conditions	Ratings			Unit
		min	typ	max	
Current Drain	With no input signal	13	27	39	mA
Detector Output 1	23dB μ , 30% modulation, $f_m = 1kHz$	40	80	160	mVrms
Detector Output 2	80dB μ , 30% modulation, $f_m = 1kHz$	90	160	230	mVrms
Signal-to-Noise Ratio 1	23dB μ , 30% modulation, $f_m = 1kHz$	17	23		dB
Signal-to-Noise Ratio 2	80dB μ , 30% modulation, $f_m = 1kHz$	46	52		dB
Total Harmonic Distortion 1	80dB μ , 30% modulation, $f_m = 1kHz$		0.4	1.1	%
Total Harmonic Distortion 2	107dB μ , 30% modulation, $f_m = 1kHz$		0.5	1.3	%
SD Sensitivity	0% modulation	11	20	29	dB μ
Local Oscillator Buffer Output	With no input signal	100	140	200	mVrms
IF Counter Buffer Output	23dB μ	140	285	400	mVrms

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Package Dimensions

unit : mm
3175B



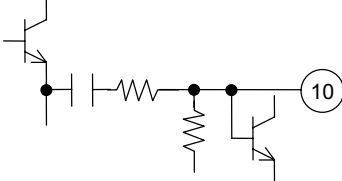
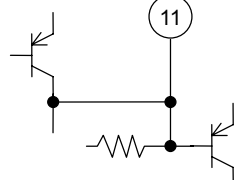
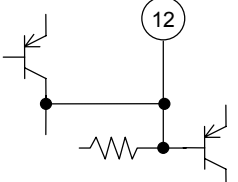
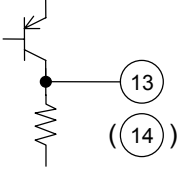
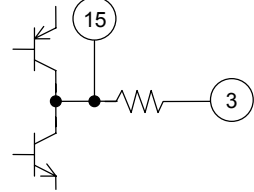
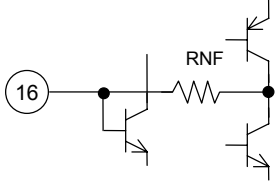
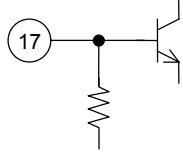
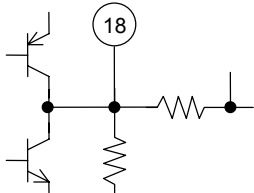
Pin Description

Pin No.	Pin function	Pin voltage	Equivalent circuit	Notes
1	FM IF input	Vreg		Input impedance $r_i = 330\Omega$
2	AM mixer output	V _{CC}		Connect the mixer coil between this pin and V _{CC}
3	REG	2.1		Vreg = 2.1V
4	AM IF input	Vreg		Input impedance $r_i = 2k\Omega$
5	GND	0V		
6	Tu-LED	V _{CC}		Active low Open collector
7	ST-LED/AF-IF output			
8	FM detector	V _{CC}		The 600BEAS-10471 (Toko Mfg. Co., Ltd.) is recommended for detector coil.
9	V _{CC}			

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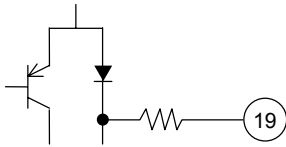
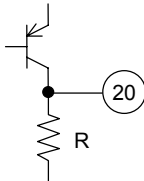
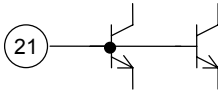
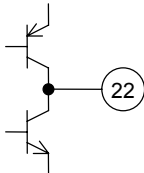
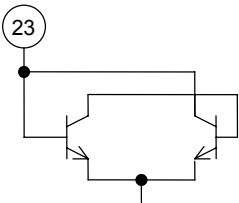
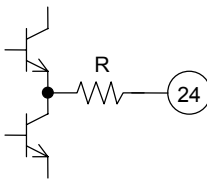
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Pin No.	Pin function	Pin voltage	Equivalent circuit	Notes
10	AM/FM IF counter output, output control switch, mute switch	0V		$V_{10} \leq 0.5V$: Reception state $1.4V \leq V_{10} \leq 2.2V$: Muting on $V_{10} \geq 3.5V$: IF counter output and muting on
11	Phase comparator low-pass filter (AM/FM switching)	$V_{CC}-1.0$		The device operates in AM mode when a current of over $200\mu A$ flows from pin. 12.
12	Pilot detector low-pass filter (Forced mono) (VCO stop)	$V_{CC}-1.0$		The device is forced to monaural when a current of over $50\mu A$ flows from this pin. The VCO is stopped when a current of over $200\mu A$ flows from this pin. The limit values for the resistor are the same as those for pin 11.
13 14	L outputs R outputs	3.2V		Output impedance $r_o = 3.3k\Omega$
15	Pilot canceler output	Vreg		
16	Decoder input	Vreg		Inverting input pin $RNF = 20k\Omega$
17	PLL input	Vreg		Input impedance $r_i = 20k\Omega$
18	FM demodulator output	$V_{reg}+0.7$		Output impedance $r_o = 2.3k\Omega$ The channel separation can be adjusted with an external capacitor connected between this pin and ground.

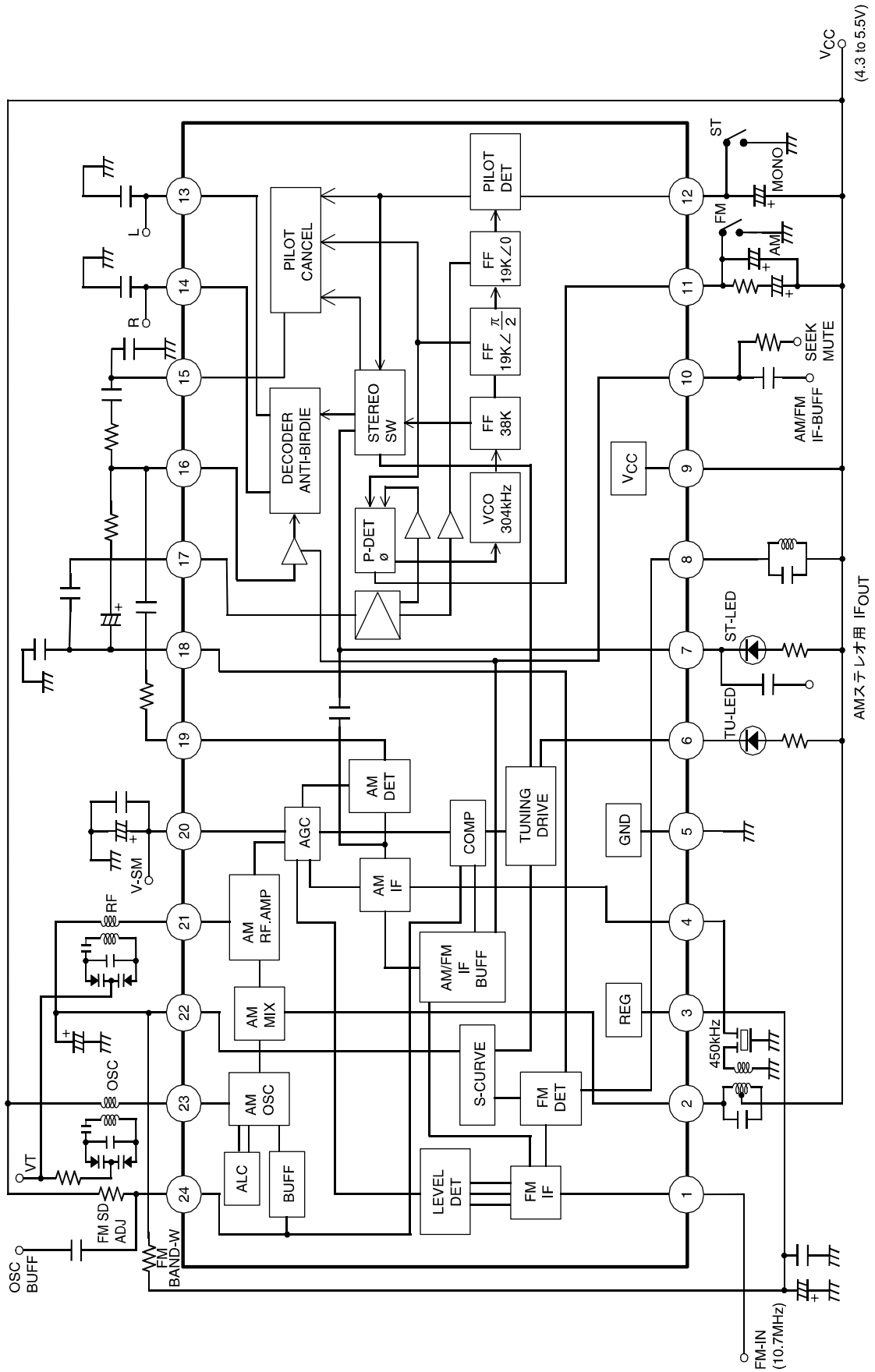
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Pin No.	Pin function	Pin voltage	Equivalent circuit	Notes
19	AM detector output	0V (FM) 1.5V (AM)		Output impedance $r_o = 3.3k\Omega$
20	S meter, AM AGC	0.2V (FM) 0.9V (AM)		The resistance of the built-in resistor R is 13.9kΩ. The SD response during seek operation is determined with the external capacitor connected to this pin.
21	AM RF input	Vreg		Must be used at the same potential as pin 22.
22	AFC	Vreg		The FM SD bandwidth can be adjusted with the external resistor connected between this pin and pin 3 (Vreg).
23	OSC	V _{CC}		Connect the oscillator coil between this pin and pin 9 (V _{CC}). Note : Impedance of the secondary oscillator coil must be 5kΩ or higher.
24	Oscillator buffer output, FM SD sensitivity adjustment	V _{CC} -1.4		The FM SD sensitivity can be adjusted with an external resistor connected to this pin. Output impedance R = 200Ω Note : Resistance of the external resistor connected to the pin 24 must be 3.3kΩ or higher.

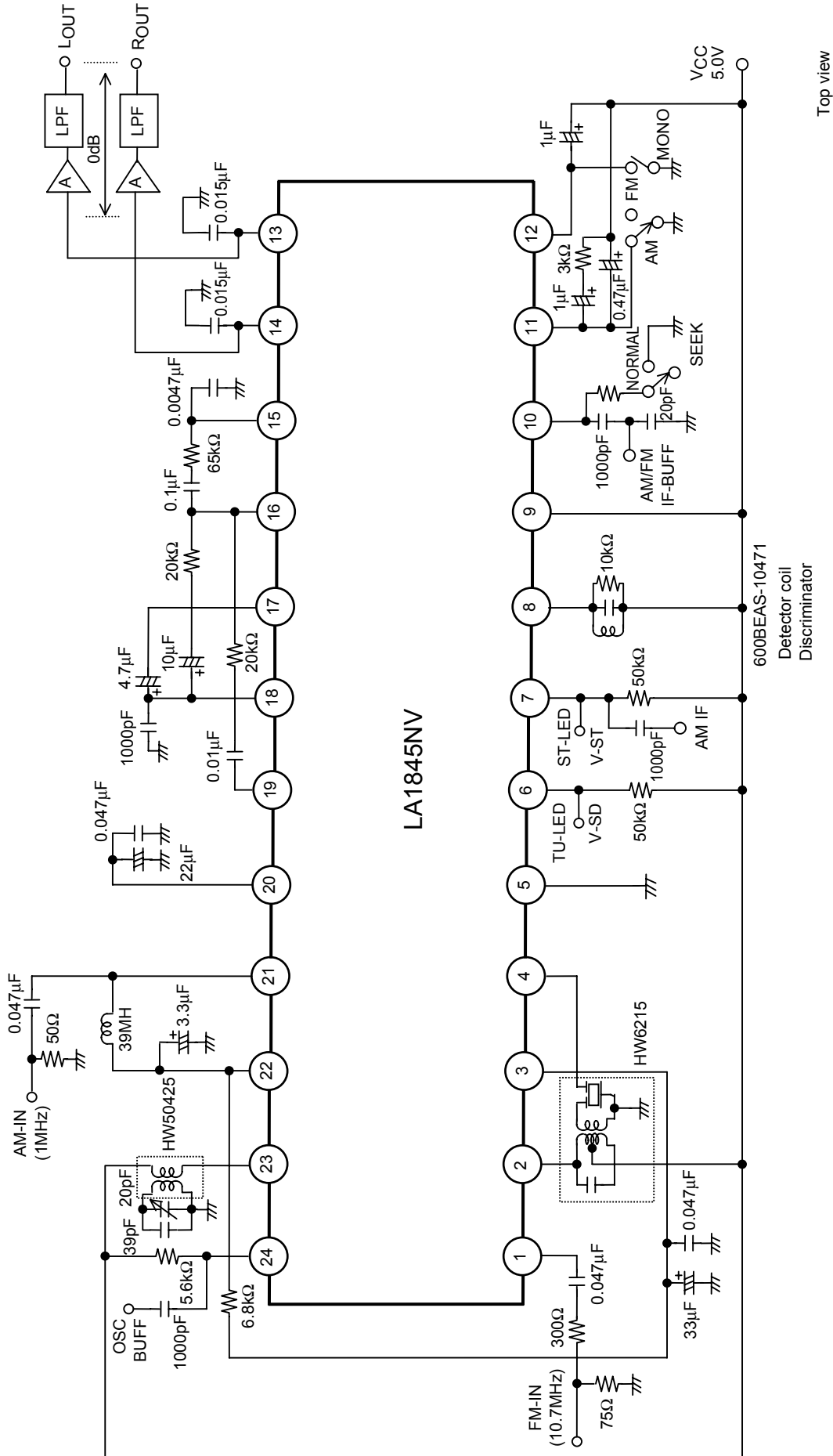
Equivalent Circuit Block Diagram



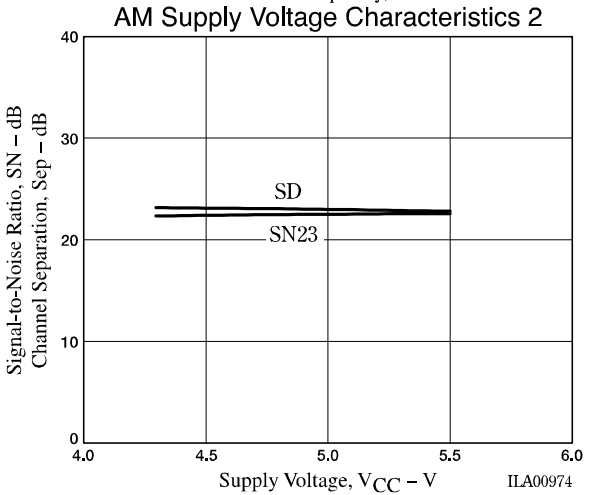
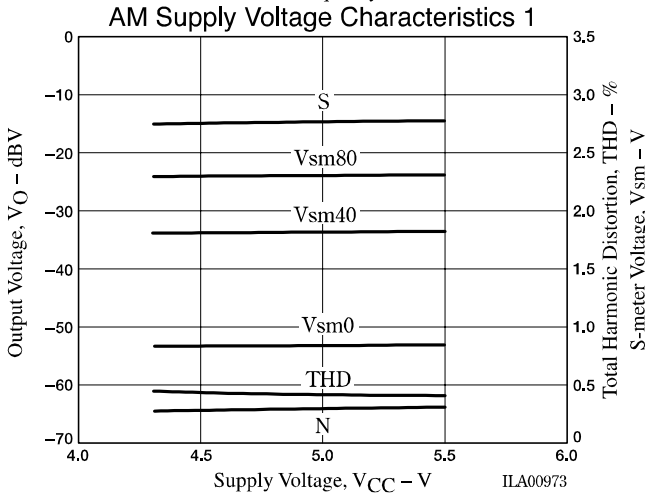
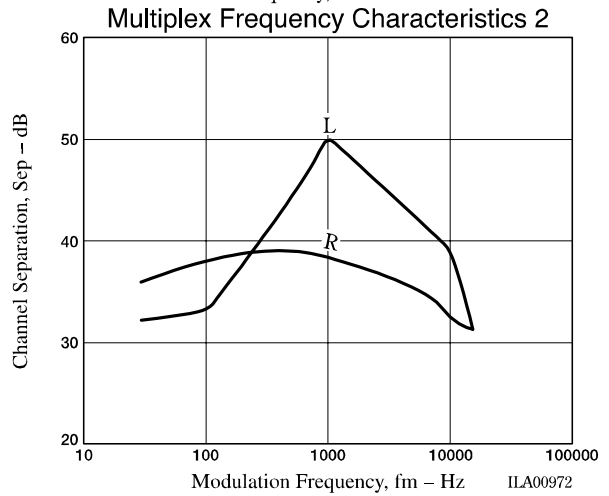
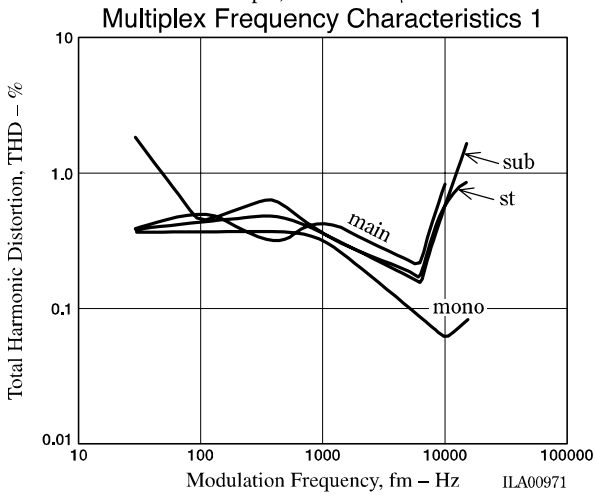
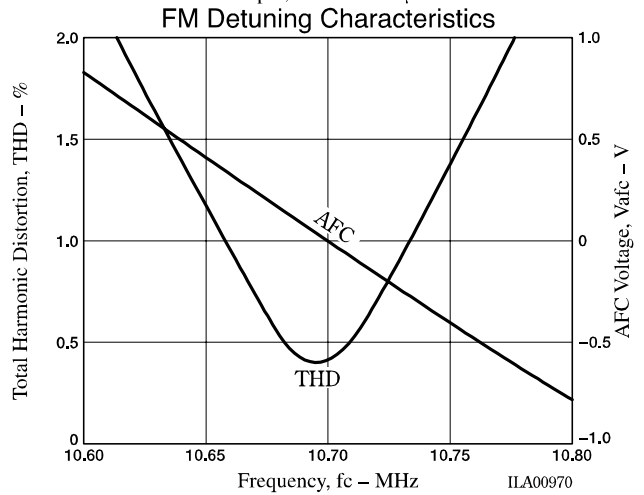
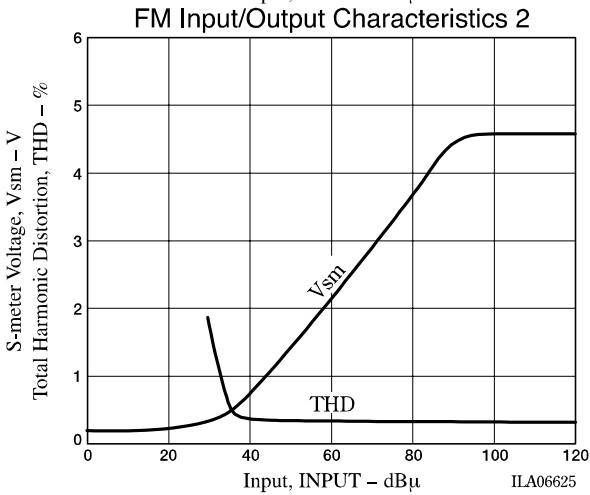
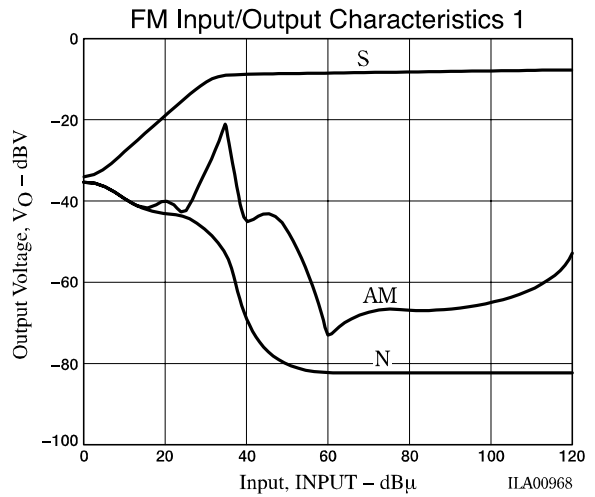
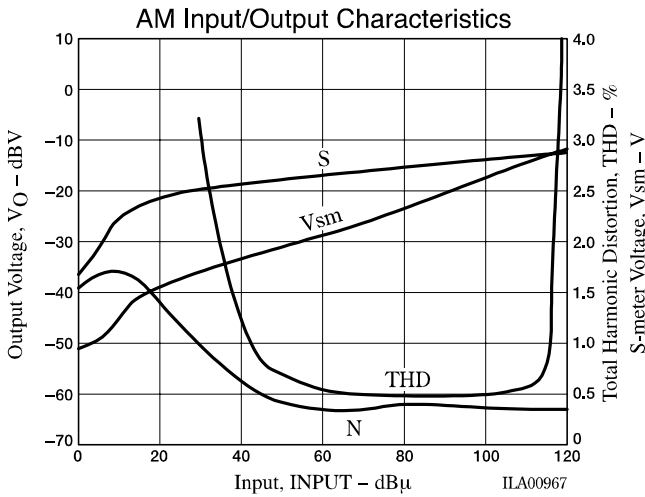
Top View

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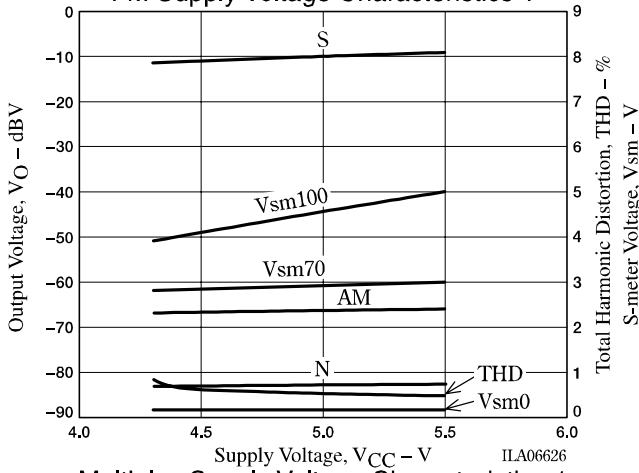
Test Circuit



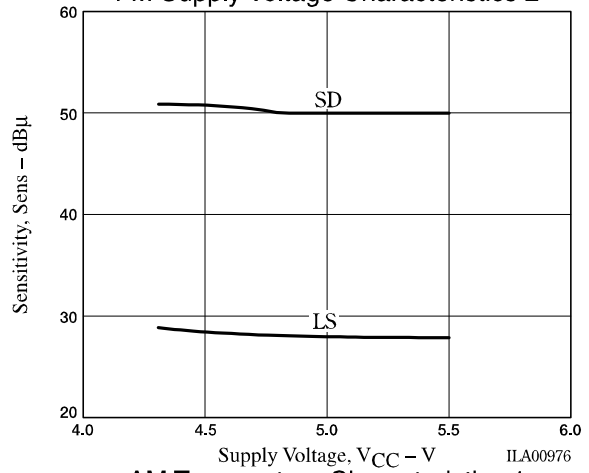
Top view



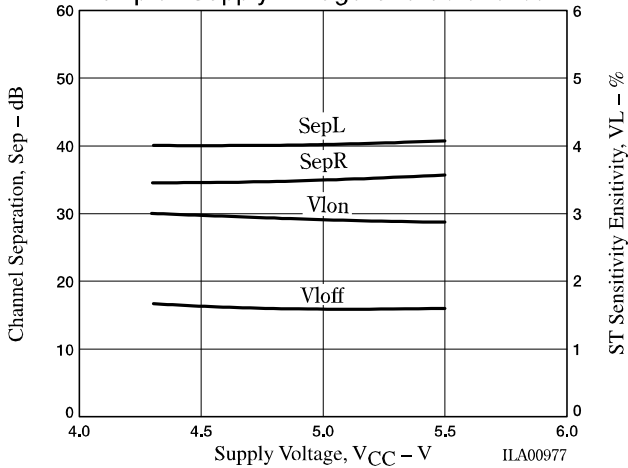
FM Supply Voltage Characteristics 1



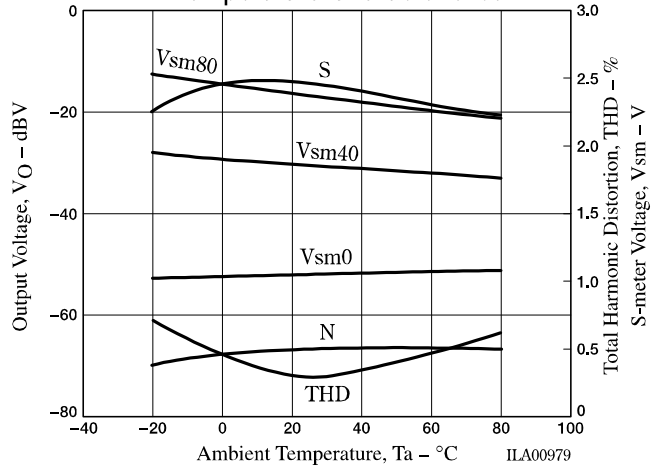
FM Supply Voltage Characteristics 2



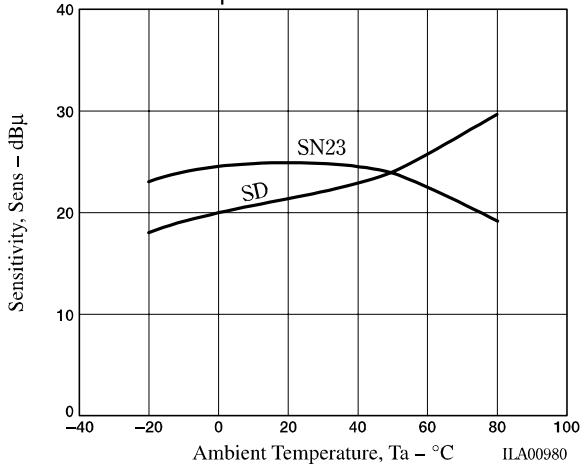
Multiplex Supply Voltage Characteristics 1



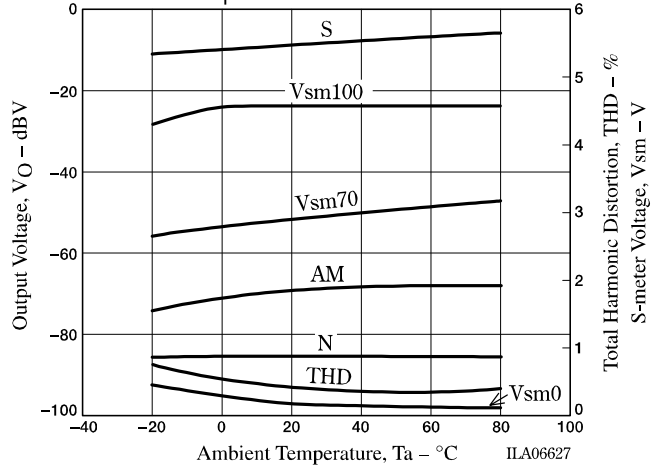
AM Temperature Characteristics 1



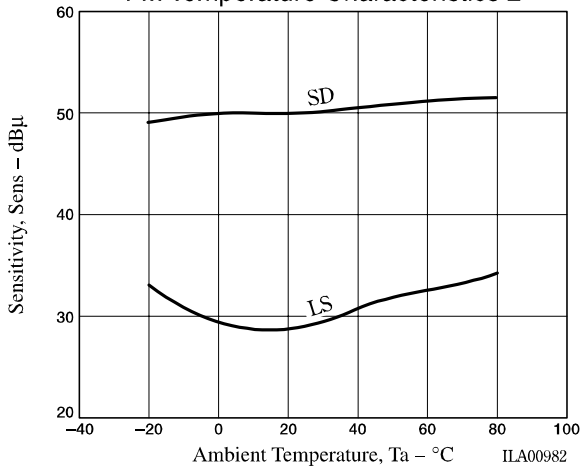
AM Temperature Characteristics 2



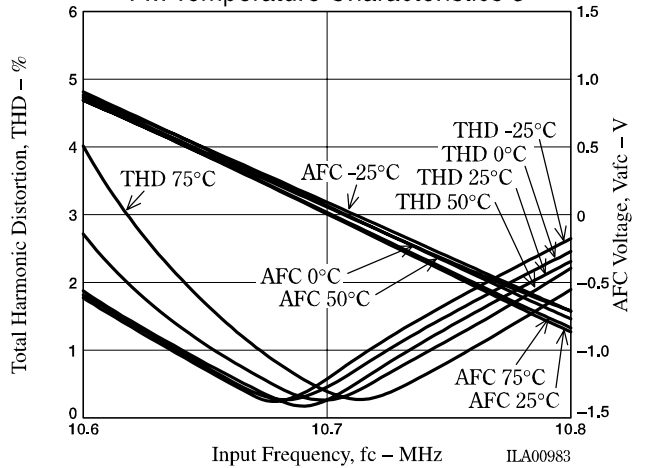
FM Temperature Characteristics 1



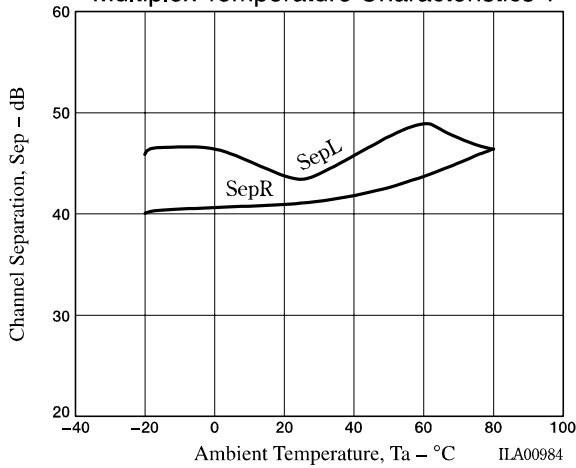
FM Temperature Characteristics 2



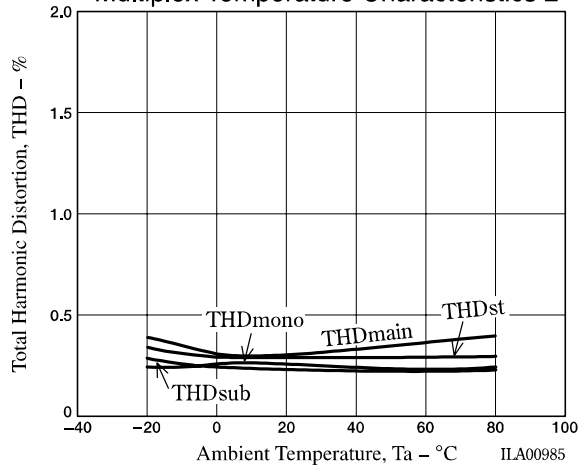
FM Temperature Characteristics 3



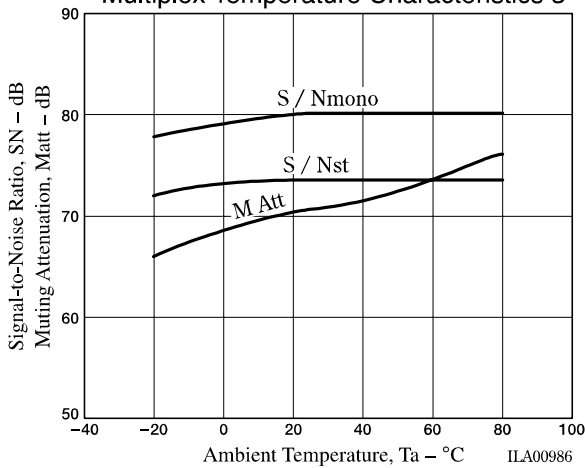
Multiplex Temperature Characteristics 1



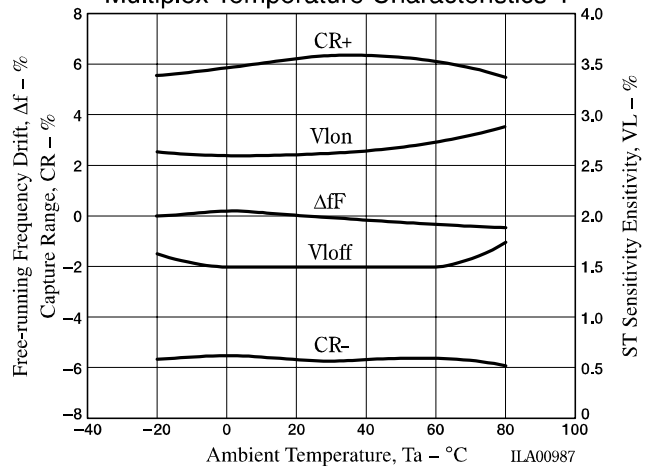
Multiplex Temperature Characteristics 2



Multiplex Temperature Characteristics 3



Multiplex Temperature Characteristics 4



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